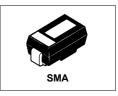
International **ISPR** Rectifier

SCHOTTKY RECTIFIER

MBRA120

1.0 Amp



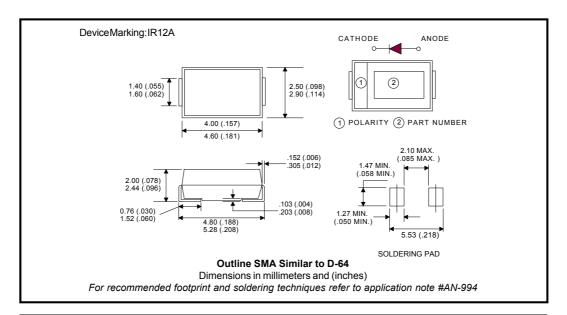
Major Ratings and Characteristics

Cha	racteristics	MBRA120	Units
I _{FAV}	Rect. Waveform	1.0	A
V _{RRM}		20	V
I _{FSM}	@tp=5µssine	310	A
V _F	@1.0Apk,T _J =125°C	0.34	V
Т _Ј	range	- 65 to 150	°C

Description/Features

The MBRA120 surface mount Schottky rectifier has been designed for applications requiring low forward drop and very small foot prints on PC boards. Typical applications are in disk drives, switching power supplies, converters, free-wheeling diodes, battery charging, and reverse battery protection.

- Small foot print, surface mountable
- Low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability



MBRA120

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International **IOR** Rectifier

Voltage Ratings

	Part number	MBRA120	
V _R	Max. DC Reverse Voltage (V)	~	
V _{RWM} Max. Working Peak Reverse Voltage (V)		20	

Absolute Maximum Ratings

	Parameters	Value	Units	Conditions	
I _{F(AV)}	Max. Average Forward Current	1.0	A	50%duty cycle@T _L =136°C,re	ctangular wave form
I _{FSM}	Max.PeakOneCycleNon-Repetitive	310		5µs Sine or 3µs Rect. pulse	Following any rated load condition and
	SurgeCurrent	40		10ms Sine or 6ms Rect. pulse	with rated V _{RRM} applied
E _{AS}	Non Repetitive Avalanche Energy	3	mJ	T _J =25°C, I _{AS} =1A, L=10mH	
I _{AR}	Repetitive Avalanche Current	0.8	A		

Electrical Specifications

	Parameters	Тур.	Max.	Units	Conditio	าร
V _{FM}	Max. Forward Voltage Drop (1)	0.42	0.45	V	@ 1A	T = 25 °C
		0.46	0.52	V	@ 2A	T _J = 25 °C
		0.33	0.37	V	@ 1A	T = 100 °C
		0.39	0.45	V	@ 2A	T _J = 100 °C
		0.30	0.35	V	@ 1A	T = 125 °C
		0.36	0.43	V	@ 2A	1 _J = 125 C
I _{RM}	Max. Reverse Leakage Current (1)	0.015	0.2	mA	Т _Ј = 25 °С	
		2.0	6.0	mA	Т _Ј = 100 °С	V_R = rated V_R
		7.0	20	mA	Т _Ј = 125 °С	
CT	Typical Junction Capacitance	110	-	pF	V _R = 5V _{DC} (te	est signal range 100kHz to
					1Mhz), @ 25	°C
Ls	Typical Series Inductance	2.0	-	nH	Measured lead to lead 5mm from package body	
dv/dt	Max. Voltage Rate of Change	-	10000	V/ µs	(Rated V _R)	

(1) Pulse Width < 300µs, Duty Cycle < 2%

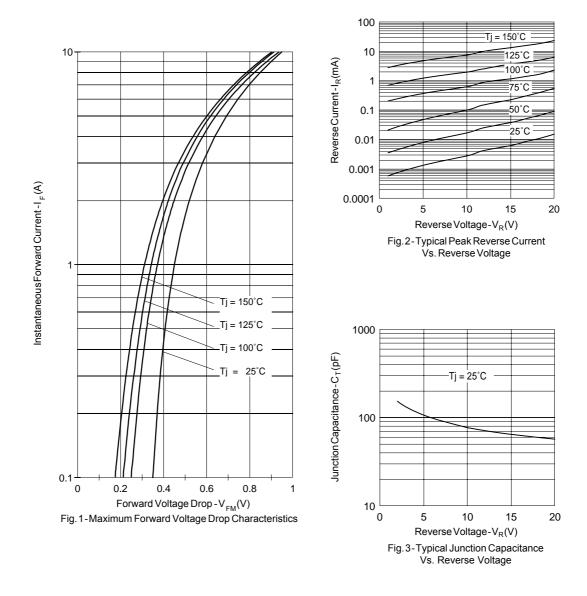
Thermal-Mechanical Specifications

	Parameters	Value	Units	Conditions
T _J	Max.JunctionTemperatureRange (*)	-65 to 150	°C	
T _{stg}	Max. Storage Temperature Range	-65 to 150	°C	
R _{thJL}	Max. Thermal Resistance Junction to Lead (**)	35	°C/W	DCoperation
R _{thJA}	Max.ThermalResistanceJunction	80	°C/W	
	toAmbient			
Wt	ApproximateWeight	0.07(0.002)	gr(oz)	
	Case Style	SMA		SimilarD-64
	DeviceMarking	IR12A		

 $\frac{(*)}{dT_j} < \frac{1}{Rth(j-a)}$ thermal runaway condition for a diode on its own heatsink

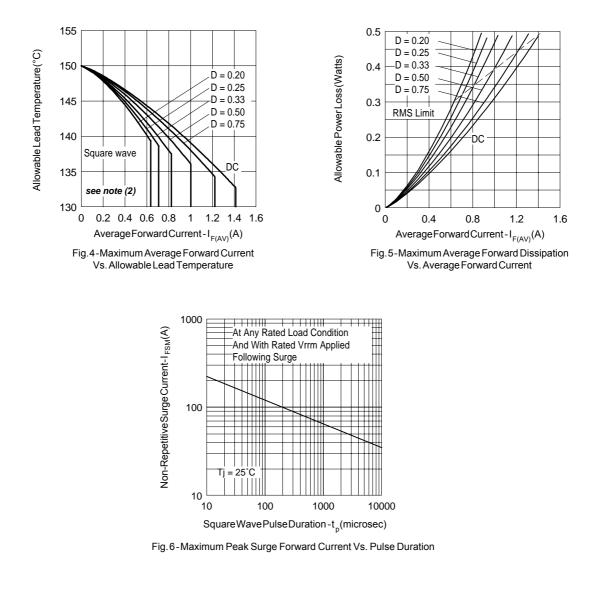
(**) Mounted 1 inch square PCB

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International



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(2) Formula used: T_{c} = T_{j} - (Pd + Pd_{REV}) \times R_{thJC};

Pd = Forward Power Loss = I_{F(AV)} \times V_{FM} @ (I_{F(AV)} / D) (see Fig. 6);

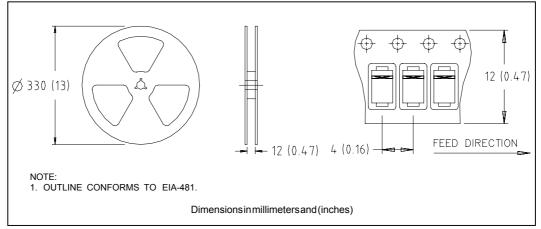
Pd_{REV} = Inverse Power Loss = V_{R4} \times I_{R} (1 - D)
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International

MBRA120

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Tape & Reel Information



Marking & Identification

Ordering Information

Each device has marking and identification on two rows. - The first row designates the device as manufactured by International Rectifier as indicated by the letters "IR", then Current, Voltage. - The second row shows the data code: Year and Week.	MBRA120TR - TAPE AND REEL WHEN ORDERING, INDICATE THE PART NUMBER AND THE QUANTITY (IN MULTIPLES OF 7500 PIECES).		
See below marking diagram.	EXAMPLE: MBRA120TR-15000PIECES		
FIRST ROW IR 12 A			
SECOND ROW Date Code YY WW			

Data and specifications subject to change without notice. This product has been designed for Industrial Level. Qualification Standards can be found on IR's Web site.

International

IR WORLD HEADQUARTERS: 233 Kansas St., El Segundo, California 90245, USA Tel: (310) 252-7105 TAC Fax: (310) 252-7309 Visit us at www.irf.com for sales contact information. 03/02